NSN 5962-00-739-5274

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View Online at https://aerobasegroup.com/nsn/5962-00-739-5274
Body Length:
Between 0.770 inches and 0.790 inches
Body Width:
Between 0.375 inches and 0.385 inches
Body Height:
Between 0.052 inches and 0.062 inches
Maximum Power Dissipation Rating:
625.0 milliwatts
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and w/decoded output
nclosure Material:
Ceramic and glass
nclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
18 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
06840-6088465 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
28 flat leads
Shelf Life:
N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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